Serial No. 10/627,983 Docket No. T36-158111M/RS (NGB.274)

AMENDMENTS TO THE ABSTRACT:

Please replace the Abstract with the following amended Abstract:

A scintillator <u>includes</u> is made of a Group III nitride compound semiconductor layer <u>that emits fluorescent light when radiated by, for example, a CU-Kα-ray source, an X-ray source, or a γ-ray source, and a scintillation counter including a scintillator having a Group III nitride compound semiconductor.</u>

[marked corrected version]

[attach 2nd page - clean correct version]

(NGB.274)

ABSTRACT OF THE DISCLOSURE

A scintillator includes a Group III nitride compound semiconductor layer that emits fluorescent light when radiated by, for example, a CU-K α -ray source, an X-ray source, or a γ -ray source, and a scintillation counter including a scintillator having a Group III nitride compound semiconductor.